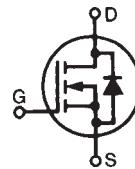
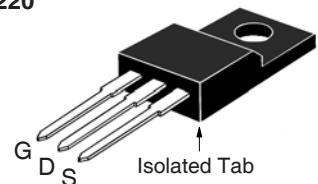


**X-Class HiPERFET  
Power MOSFET**
**IXFP4N85XM**
**(Electrically Isolated Tab)**
**N-Channel Enhancement Mode**


**$V_{DSS}$**  = 850V  
 **$I_{D25}$**  = 3.5A  
 **$R_{DS(on)}$**  ≤ 2.5Ω

**OVERMOLDED  
TO-220**


G = Gate      D = Drain  
 S = Source

Symbol	Test Conditions	Maximum Ratings	
$V_{DSS}$	$T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$	850	V
$V_{DGR}$	$T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ , $R_{GS} = 1\text{M}\Omega$	850	V
$V_{GSS}$	Continuous	±30	V
$V_{GSM}$	Transient	±40	V
$I_{D25}$	$T_c = 25^\circ\text{C}$ , Limited by $T_{JM}$	3.5	A
$I_{DM}$	$T_c = 25^\circ\text{C}$ , Pulse Width Limited by $T_{JM}$	10.0	A
$I_A$	$T_c = 25^\circ\text{C}$	2	A
$E_{AS}$	$T_c = 25^\circ\text{C}$	125	mJ
$dv/dt$	$I_s \leq I_{DM}$ , $V_{DD} \leq V_{DSS}$ , $T_J \leq 150^\circ\text{C}$	50	V/ns
$P_D$	$T_c = 25^\circ\text{C}$	35	W
$T_J$		-55 ... +150	°C
$T_{JM}$		150	°C
$T_{stg}$		-55 ... +150	°C
$T_L$	Maximum Lead Temperature for Soldering	300	°C
$T_{SOLD}$	1.6 mm (0.062in.) from Case for 10s	260	°C
$V_{ISOL}$	50/60 Hz, 1 Minute	2500	V~
$M_d$	Mounting Torque	1.13 / 10	Nm/lb.in
<b>Weight</b>		2.5	g

Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
$BV_{DSS}$	$V_{GS} = 0\text{V}$ , $I_D = 250\mu\text{A}$	850		V
$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250\mu\text{A}$	3.0		V
$I_{GSS}$	$V_{GS} = \pm 30\text{V}$ , $V_{DS} = 0\text{V}$			±100 nA
$I_{DSS}$	$V_{DS} = V_{DSS}$ , $V_{GS} = 0\text{V}$ $T_J = 125^\circ\text{C}$			5 μA 500 μA
$R_{DS(on)}$	$V_{GS} = 10\text{V}$ , $I_D = 2\text{A}$ , Note 1			2.5 Ω

**Features**

- International Standard Package
- Plastic Overmolded Tab
- Low  $R_{DS(on)}$  and  $Q_G$
- 2500V~ Electrical Isolation
- Avalanche Rated
- Low Package Inductance

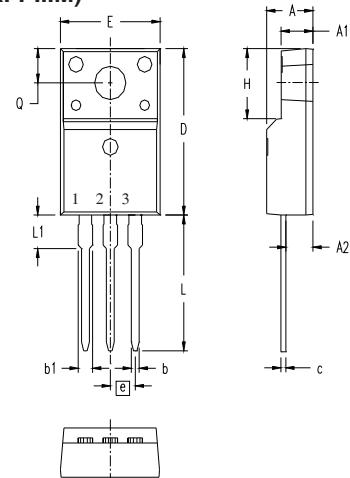
**Advantages**

- High Power Density
- Easy to Mount
- Space Savings

**Applications**

- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- Robotics and Servo Controls

Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max
$g_{fs}$	$V_{DS} = 10\text{V}$ , $I_D = 2\text{A}$ , Note 1	1.2	2.0	S
$R_{Gi}$	Gate Input Resistance		3	$\Omega$
$C_{iss}$	$V_{GS} = 0\text{V}$ , $V_{DS} = 25\text{V}$ , $f = 1\text{MHz}$	247		pF
$C_{oss}$		305		pF
$C_{rss}$		5		pF
<b>Effective Output Capacitance</b>				
$C_{o(er)}$	Energy related } $V_{GS} = 0\text{V}$	27		pF
$C_{o(tr)}$	Time related } $V_{DS} = 0.8 \cdot V_{DSS}$	60		pF
$t_{d(on)}$	$V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 2\text{A}$ $R_G = 30\Omega$ (External)	13		ns
$t_r$		27		ns
$t_{d(off)}$		28		ns
$t_f$		20		ns
$Q_{g(on)}$	$V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 2\text{A}$	7.0		nC
$Q_{gs}$		2.3		nC
$Q_{gd}$		3.3		nC
$R_{thJC}$			3.57	$^\circ\text{C}/\text{W}$
$R_{thCS}$		0.50		$^\circ\text{C}/\text{W}$

**OVERMOLDED TO-220  
(IXFP...M)**

Terminals: 1 - Gate  
2 - Drain  
3 - Source

SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.177	.193	4.50	4.90
A1	.092	.108	2.34	2.74
A2	.101	.117	2.56	2.96
b	.028	.035	0.70	0.90
b1	.050	.058	1.27	1.47
c	.018	.024	0.45	0.60
D	.617	.633	15.67	16.07
E	.392	.408	9.96	10.36
e	.100	BSC	2.54	BSC
H	.255	.271	6.48	6.88
L	.499	.523	12.68	13.28
L1	.119	.135	3.03	3.43
$\emptyset P$	.121	.129	3.08	3.28
Q	.126	.134	3.20	3.40

**Source-Drain Diode**

Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max
$I_s$	$V_{GS} = 0\text{V}$		4	A
$I_{sm}$	Repetitive, pulse Width Limited by $T_{JM}$		16	A
$V_{SD}$	$I_F = I_S$ , $V_{GS} = 0\text{V}$ , Note 1		1.4	V
$t_r$	$I_F = 2\text{A}$ , $-di/dt = 100\text{A}/\mu\text{s}$	170		ns
$Q_{RM}$		770		nC
$I_{RM}$	$V_R = 100\text{V}$	9		A

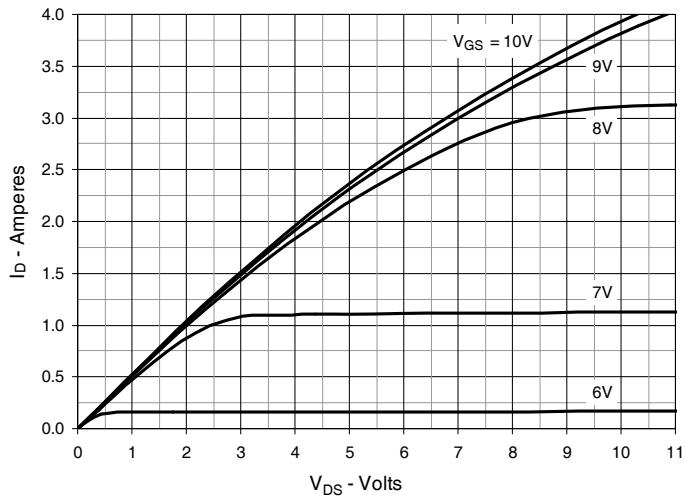
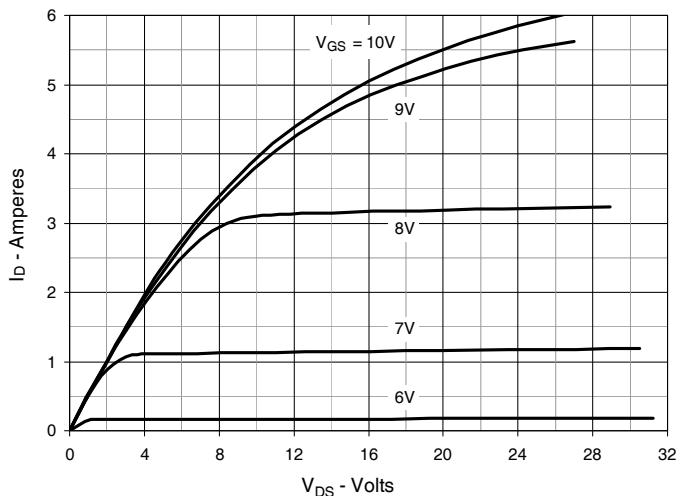
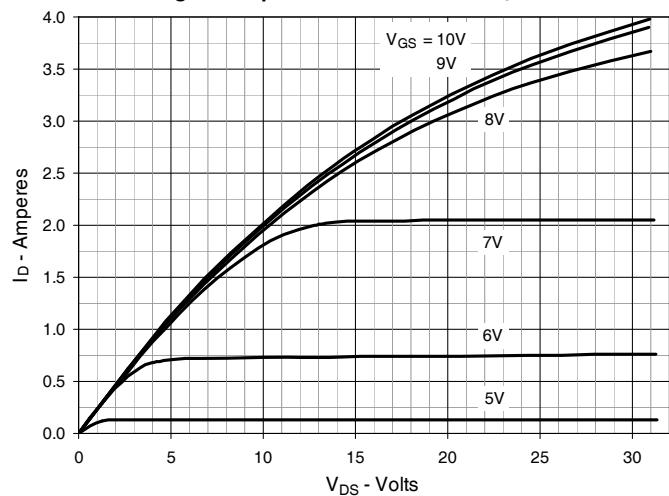
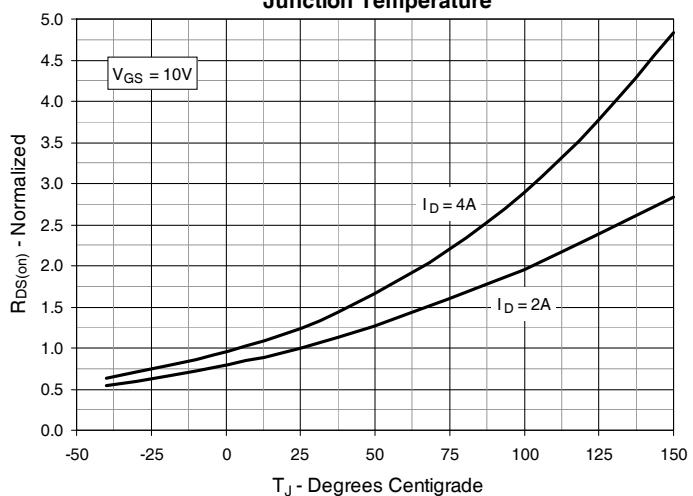
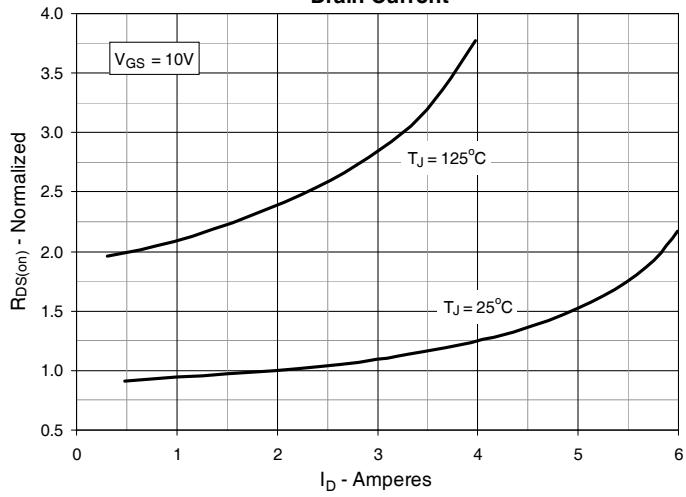
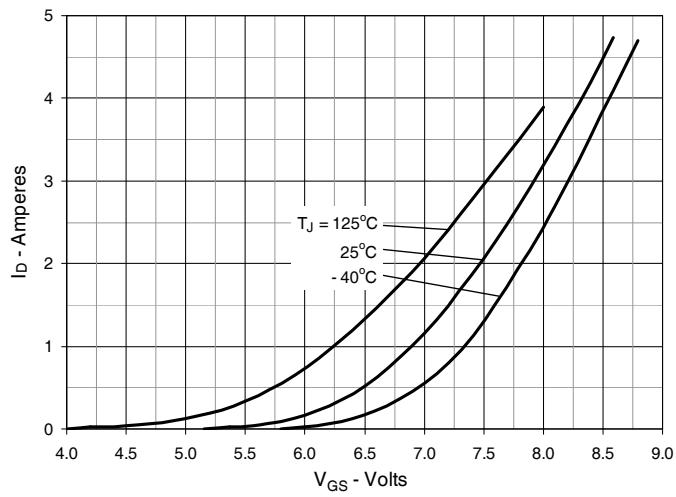
Note 1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .

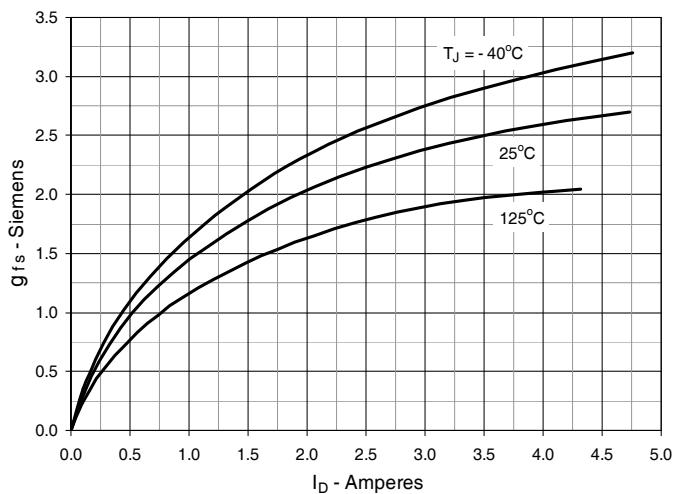
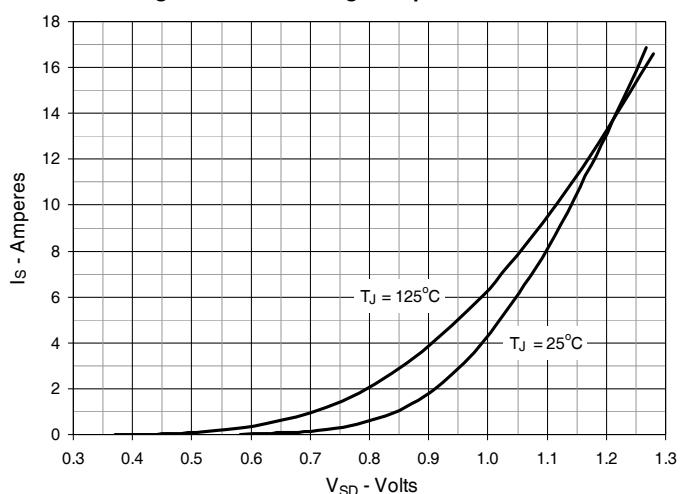
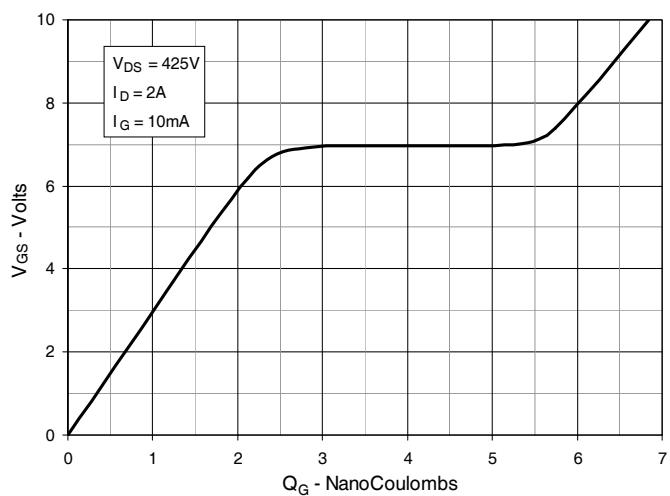
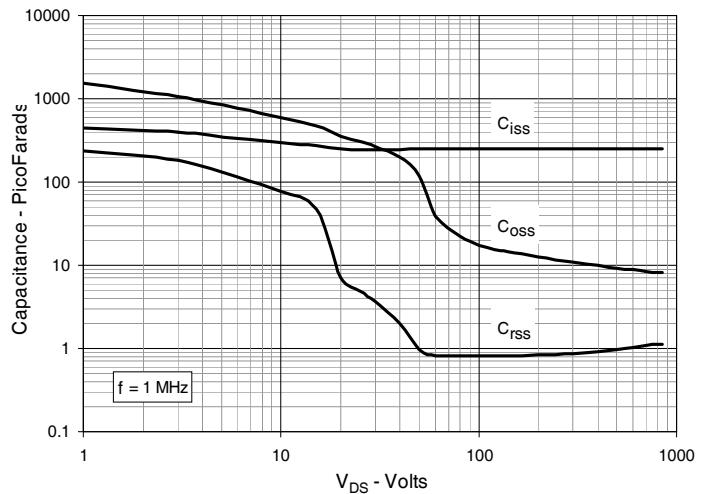
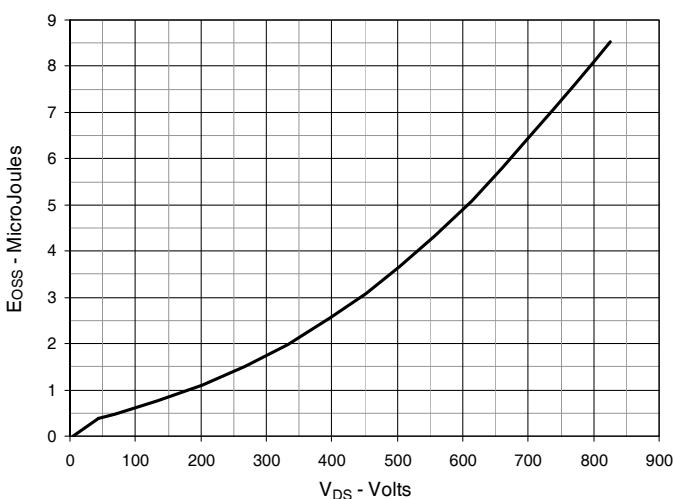
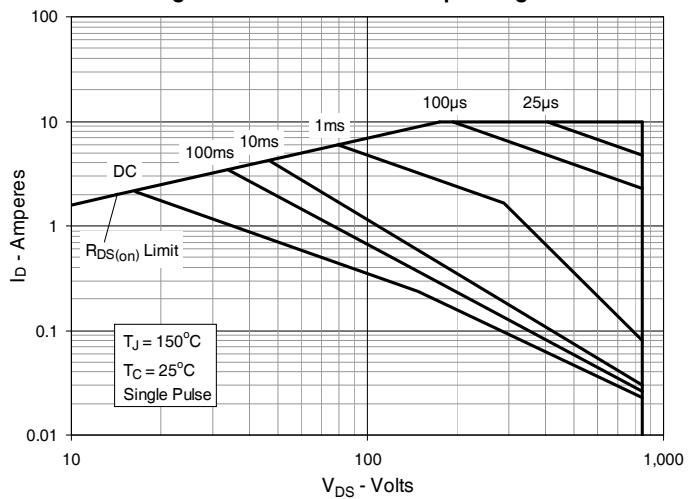
**PRELIMINARY TECHNICAL INFORMATION**

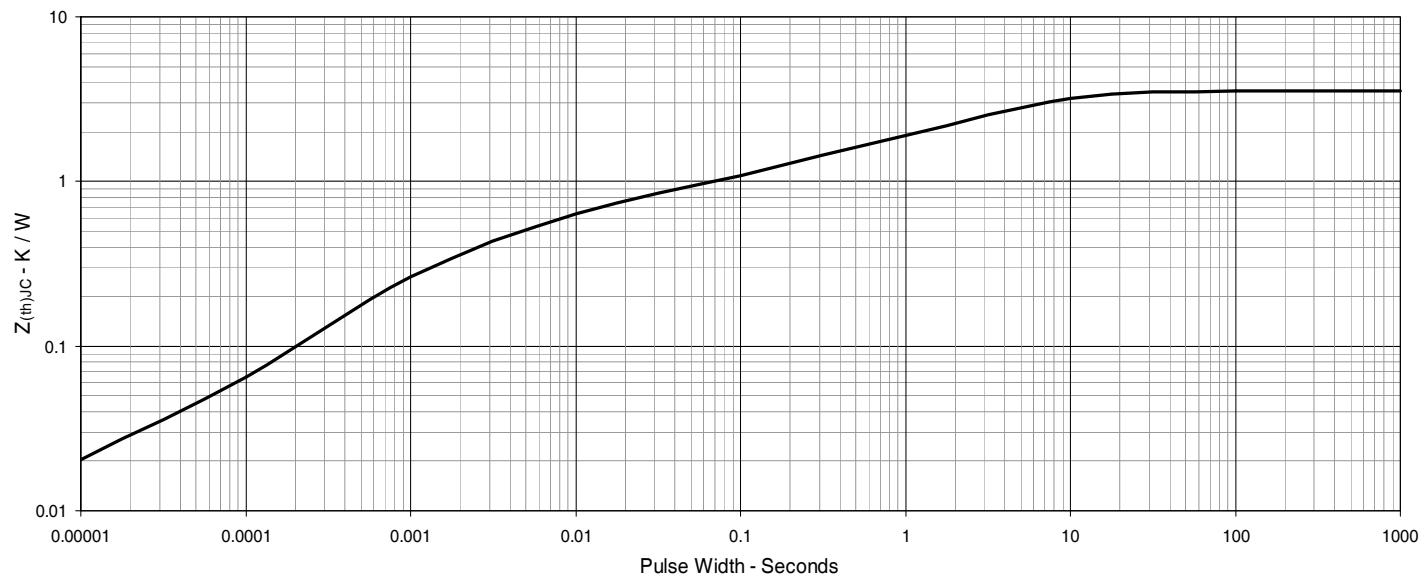
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IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: 4,835,592 4,931,844 5,049,961 5,237,481 6,162,665 6,404,065B1 6,683,344 6,727,585 7,005,734B2 7,157,338B2 4,860,072 5,017,508 5,063,307 5,381,025 6,259,123B1 6,534,343 6,710,405B2 6,759,692 7,063,975B2 4,881,106 5,034,796 5,187,117 5,486,715 6,306,728B1 6,583,505 6,710,463 6,771,478B2 7,071,537

**Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$** **Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$** **Fig. 3. Output Characteristics @  $T_J = 125^\circ\text{C}$** **Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 2\text{A}$  Value vs. Junction Temperature****Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D = 2\text{A}$  Value vs. Drain Current****Fig. 6. Input Admittance**

**Fig. 7. Transconductance****Fig. 8. Forward Voltage Drop of Intrinsic Diode****Fig. 8. Gate Charge****Fig. 9. Capacitance****Fig. 11. Output Capacitance Stored Energy****Fig. 12. Forward-Bias Safe Operating Area**

**Fig. 13. Maximum Transient Thermal Impedance**

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